## NSN 5961-01-239-4504

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View Online at https://aerobasegroup.com/nsn/5961-01-239-4504 **Inclosure Material:** Glass **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 550.0 collector-to-emitter, with voltage between base and emitter and 400.0 collector to emitter voltage, dc with specified circuit between base and emitter and 350.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** 12.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Fiig: A110a0

No